US1A THRU US1K

SURFACE MOUNT ULTRAFAST RECTIFIER VOLTAGE - 50 to 800 Volts CURRENT - 1.0 Ampere

FEATURES

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Ultrafast recovery times for high efficiency
- Plastic package has Underwriters Laboratory
 Flammability Classification 94V-O
- Glass passivated junction
- High temperature soldering:
 260 ¢J/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC DO-214AC molded plastic

Terminals: Solder plated, solderable per MIL-STD-750,

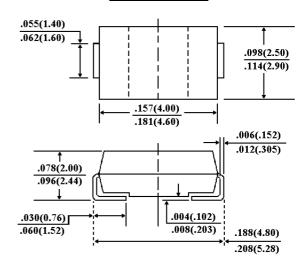
Method 2026

Polarity: Indicated by cathode band

Standard packaging: 12mm tape (EIA-481)

Weight: 0.002 ounce, 0.064 gram

SMA/DO-214AC



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 ¢J ambient temperature unless otherwise specified.

Resistive or inductive load. For capacitive load, derate current by 20%.

	SYMBOLS	US1A	US1B	US1D	US1G	US1J	US1K	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	Volts
Maximum Average Forward Rectified Current,	I _(AV)	1.0						Amps
at T _L =100 ¢J								
Peak Forward Surge Current 8.3ms single half sine-	I _{FSM}	30.0						Amps
wave superimposed on rated load(JEDEC method)								
T _A =55 ¢J								
Maximum Instantaneous Forward Voltage at 1.0A	V_{F}		1.0		1.4	1	.7	Volts
Maximum DC Reverse Current T _A =25 ¢J	I_R	10.0						£g A
At Rated DC Blocking Voltage T _A =100 ¢J		100						
Maximum Reverse Recovery Time (Note 1) T _J =25 ¢J	T_RR	50.0			100.0		nS	
Typical Junction capacitance (Note 2)	CJ	17						₽F
Maximum Thermal Resistance (Note 3)	R £KJL	30						¢J/W
Operating and Storage Temperature Range	T_J, T_{STG}	-50 to +150						¢J

NOTES:

- 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, Irr=0.25A
- 2. Measured at 1 MHz and Applied reverse voltage of 4.0 volts
- 3. 8.0mm² (.013mm thick) land areas

RATING AND CHARACTERISTIC CURVES US1A THRU US1K

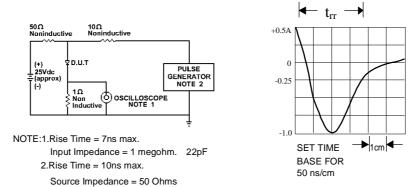
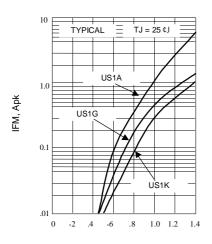


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



2.0 SINGLE PHASE HALF WAVE RESISTIVE OR INDUCTIVE P.C.B MOUNTED ON -0.315x0.315*(8.0x8.0mm) PAD AREAS

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2.5 50 75 100 125 150 175

LEAD TEMPERATURE, ¢J

Fig. 2-FORWARD CHARACTERISTICS

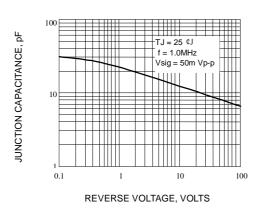


Fig. 4-TYPICAL JUNCTION CAPACITANCE



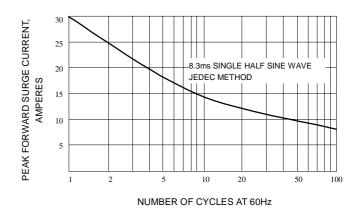


Fig. 5-PEAK FORWARD SURGE CURRENT